PNP 500mA 30V General purpose transistors

Datasheet

Parameter	Value
V_{CEO}	-30V
IC	-0.5A

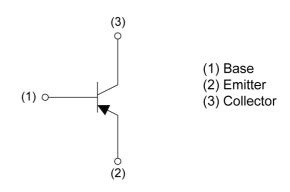
Outline

EMT3F	UMT3F
(1) (2)	(1) (2)
2SAR502EB	2SAR502UB
SOT-416FL	SOT-323FL

Features

- 1)General purpose.
- 2)Complementary NPN types: 2SCR502EB(EMT3F)/2SCR502UB(UMT3F)
- 3)Collector current is large.
- 4)Low V_{CE(sat)}.

•Inner circuit



Application

LOW FREQUENCY AMPLIFIER

Packaging specifications

Part No.	Package	Package size	Taping code	Reel size (mm)	Tape width (mm)	Basic ordering unit.(pcs)	Marking
2SAR502EB	EMT3F	1616	TL	180	8	3000	LT
2SAR502UB	UMT3F	2021	TL	180	8	3000	LT

● Absolute maximum ratings (T_a = 25°C)

Parameter			Values	Unit	
Collector-base voltage			-30	V	
Collector-emitter voltage		V_{CEO}	-30	V	
Emitter-base voltage		V _{EBO}	-6	V	
Calla atau a commant		I _C *1	-0.5	Α	
Collector current		I _{CP} *2	-1	Α	
Base current		I _B	I _B -0.15		
Davis a dissination	2SAR502EB	D *3	150	\0/	
Power dissipation	2SAR502UB	P _D *3	200	mW	
Junction temperature			150	°C	
Range of storage temperature			-55 to +150	°C	

● Electrical characteristics (T_a = 25°C)

Davameter	Cymabal	Conditions	Values			Linit
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Collector-base breakdown voltage	BV _{CBO}	I _C = -100μA	-30	-	-	V
Collector-emitter breakdown voltage	BV _{CEO}	I _C = -1mA	-30	-	-	V
Emitter-base breakdown voltage	BV _{EBO}	I _E = -100μA	-6	-	-	V
Collector cut-off current	I _{CBO}	V _{CB} = -25V	-	-	-200	nA
Emitter cut-off current	I _{EBO}	V _{EB} = -4V	-	-	-200	nA
Collector-emitter saturation voltage	V _{CE(sat)}	I _C = -200mA, I _B = -10mA	-	-150	-400	mV
DC current gain	h _{FE}	$V_{CE} = -2V, I_{C} = -100 \text{mA}$	200	-	500	-
Transition frequency	f _T *4	V _{CE} = -10V, I _E = 100mA, f = 100MHz	-	520	-	MHz
Output capacitance	C _{ob}	V _{CB} = 10V, I _E = 0A, f = 1MHz	-	4	-	pF

^{*1} Limited by power dissipation.

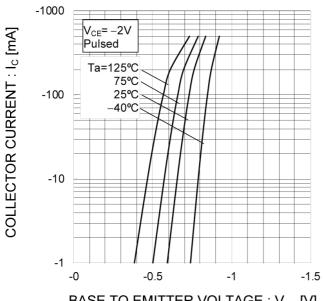
^{*2} Pw=10ms, Single pulse.

^{*3} Each terminal mounted on a reference land.

^{*4} Pulsed

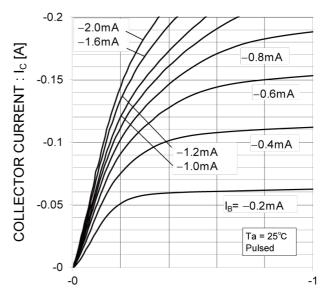
● Electrical characteristic curves(T_a = 25°C)

Fig.1 Grounded Emitter Propagation Characteristics



BASE TO EMITTER VOLTAGE: VBE [V]

Fig.2 Typical Output Characteristics



COLLECTOR TO EMITTER VOLTAGE: VCE [V]

Fig.3 DC Current Gain vs. Collector Current(I)

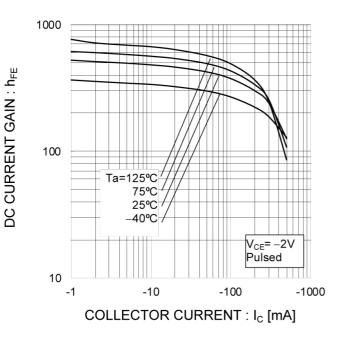
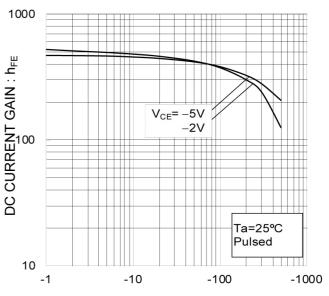


Fig.4 DC Current Gain vs. Collector Current(II)



COLLECTOR CURRENT : I_C [mA]

● Electrical characteristic curves(T_a = 25°C)

Fig.5 Collector-Emitter Saturation Voltage vs. Collector Current(I)

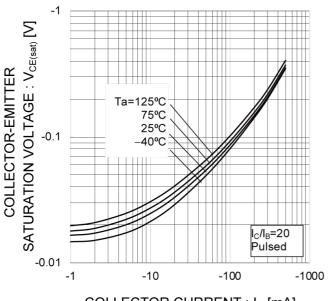
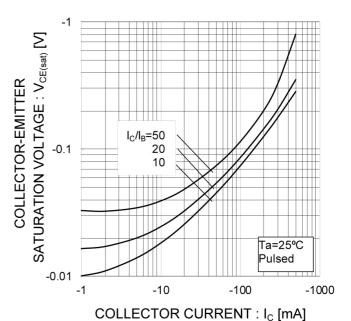


Fig.6 Collector-Emitter Saturation Voltage vs. Collector Current(II)



COLLECTOR CURRENT : I_C [mA]

Fig.7 Base-Emitter Saturation Voltage vs. Collector Current

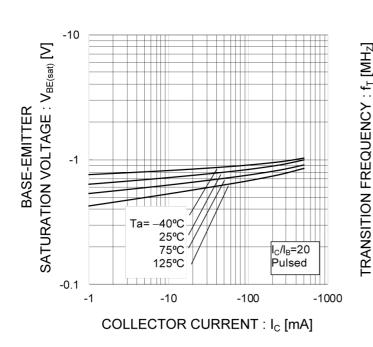
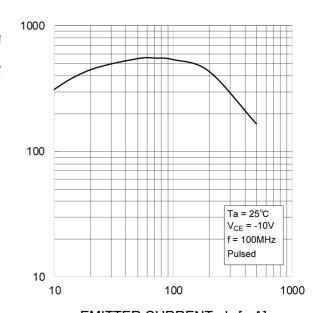


Fig.8 Gain Bandwidth Product vs. Emitter Current



EMITTER CURRENT : I_E [mA]

● Electrical characteristic curves(T_a = 25°C)

Fig.9 Emitter input capacitance vs. Emitter-Base Voltage Collector output capacitance vs. Collector-Base Voltage

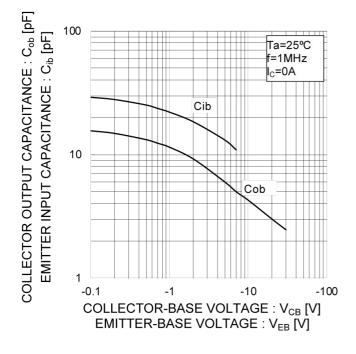


Fig.10 Safe Operating Area

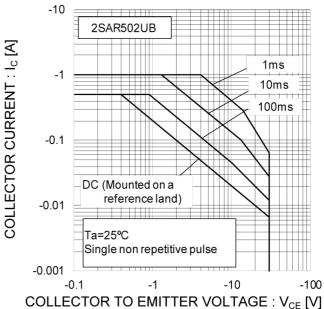
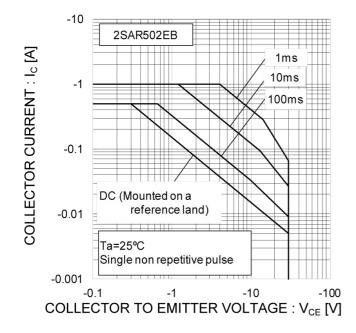
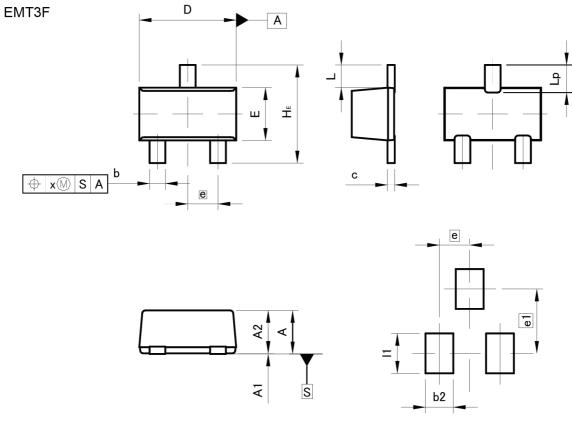


Fig.11 Safe Operating Area



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

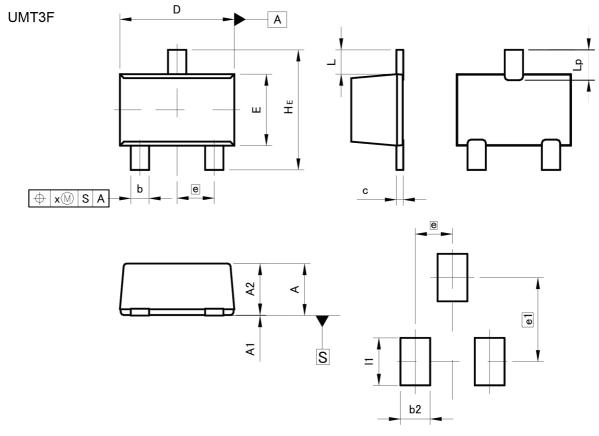
DIM	MILIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α	0.65	0.85	0.026	0.033
A1	0.00	0.10	0.000	0.004
A2	0.60	0.80	0.024	0.031
b	0.21	0.36	0.008	0.014
С	0.08	0.18	0.003	0.007
D	1.50	1.70	0.059	0.067
E	0.76	0.96	0.030	0.038
е	0.9	50	0.0	20
HE	1.50	1.70	0.059	0.067
L	0.37		0.0	15
Lp	0.35	0.55	0.014	0.022
Х	_	0.10	_	0.004

	DIM	MILIMETERS		INCHES			
		MIN	MAX	MIN	MAX		
	b2	_	0.46	-	0.018		
	e1	_	1.05	_	0.041		
	l1	_	0.65	_	0.026		

Dimension in mm/inches



Dimensions



Pattern of terminal position areas [Not a recommended pattern of soldering pads]

	MILIMETERS		INCHES		
DIM					
	MIN	MAX	MIN	MAX	
Α	0.85	1.05	0.033	0.041	
A1	0.00	0.10	0.000	0.004	
A2	0.80	1.00	0.031	0.039	
b	0.27	0.42	0.011	0.017	
С	0.08	0.18	0.003	0.007	
D	1.90	2.10	0.075	0.083	
E	1.15	1.35	0.045	0.053	
е	0.0	65	0.0	26	
HE	2.00	2.20	0.079	0.087	
L	0.4	43	0.0	117	
Lp	0.43	0.63	0.017	0.025	
х	_	0.10	_	0.004	

	DIM	MILIMETERS		INCHES		
		MIN	MAX	MIN	MAX	
	b2	-	0.52	-	0.020	
	e1	1.47		0.0	58	
	l1	-	0.83	-	0.033	

Dimension in mm/inches



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